

74AUP1G07

Low-power buffer with open-drain output

Rev. 5 — 15 November 2011

Product data sheet

1. General description

The 74AUP1G07 provides the single non-inverting buffer with open-drain output. The output of the device is an open drain and can be connected to other open-drain outputs to implement active-LOW wired-OR or active-HIGH wired-AND functions.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - ◆ JESD8-12 (0.8 V to 1.3 V)
 - ◆ JESD8-11 (0.9 V to 1.65 V)
 - ◆ JESD8-7 (1.2 V to 1.95 V)
 - ◆ JESD8-5 (1.8 V to 2.7 V)
 - ◆ JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - ◆ HBM JESD22-A114F Class 3A exceeds 5000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$



3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AUP1G07GW	−40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1
74AUP1G07GM	−40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886
74AUP1G07GF	−40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1 × 0.5 mm	SOT891
74AUP1G07GN	−40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115
74AUP1G07GS	−40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202

4. Marking

Table 2. Marking

Type number	Marking code ^[1]
74AUP1G07GW	pS
74AUP1G07GM	pS
74AUP1G07GF	pS
74AUP1G07GN	pS
74AUP1G07GS	pS

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram

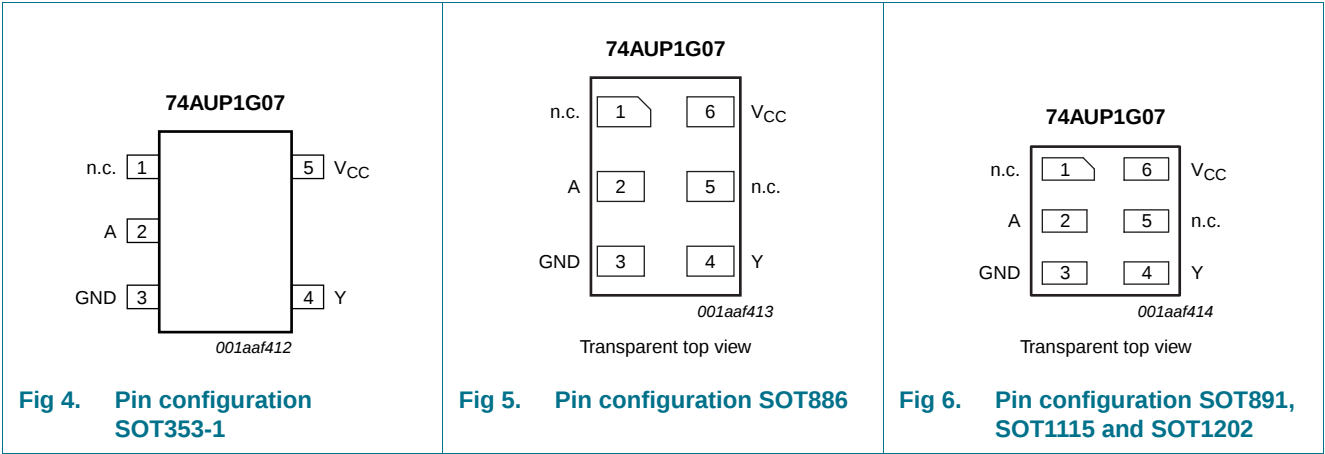
Fig 1. Logic symbol

Fig 2. IEC logic symbol

Fig 3. Logic diagram

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

Symbol	Pin		Description
	TSSOP5	XSON6	
n.c.	1	1	not connected
A	2	2	data input
GND	3	3	ground (0 V)
Y	4	4	data output
n.c.	-	5	not connected
V _{CC}	5	6	supply voltage

7. Functional description

Table 4. Function table^[1]

Input	Output
A	Y
L	L
H	Z

[1] H = HIGH voltage level;
L = LOW voltage level;
Z = high-impedance OFF state.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+4.6	V
I_{IK}	input clamping current	$V_I < 0$ V	-50	-	mA
V_I	input voltage		[1] -0.5	+4.6	V
I_{OK}	output clamping current	$V_O < 0$ V	-50	-	mA
V_O	output voltage	Active mode and Power-down mode	[1] -0.5	+4.6	V
I_O	output current	$V_O = 0$ V to V_{CC}	-	+20	mA
I_{CC}	supply current		-	50	mA
I_{GND}	ground current		-50	-	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	$T_{amb} = -40$ °C to +125 °C	[2] -	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP5 packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.

For XSON6 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		0.8	3.6	V
V_I	input voltage		0	3.6	V
V_O	output voltage	Active mode and Power-down mode	0	3.6	V
T_{amb}	ambient temperature		-40	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 0.8$ V to 3.6 V	0	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{amb} = 25$ °C						
V_{IH}	HIGH-level input voltage	$V_{CC} = 0.8$ V	$0.70 \times V_{CC}$	-	-	V
		$V_{CC} = 0.9$ V to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		$V_{CC} = 2.3$ V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0$ V to 3.6 V	2.0	-	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 0.8$ V	-	-	$0.30 \times V_{CC}$	V
		$V_{CC} = 0.9$ V to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		$V_{CC} = 2.3$ V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0$ V to 3.6 V	-	-	0.9	V

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V		
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OZ}	OFF-state output current	V _I = V _{IH} ; V _O = 0 V to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V	-	-	±0.2	μA
ΔI _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	0.5	μA
ΔI _{CC}	additional supply current	V _I = V _{CC} – 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	-	-	40	μA
C _I	input capacitance	V _{CC} = 0 V to 3.6 V; V _I = GND or V _{CC}	-	0.8	-	pF
C _O	output capacitance	output enabled; V _O = GND; V _{CC} = 0 V	-	1.7	-	pF
		output disabled; V _O = GND; V _{CC} = 0 V	-	1.1	-	pF
T _{amb} = –40 °C to +85 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V		
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.5	μA

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{OZ}	OFF-state output current	$V_I = V_{IH}$; $V_O = 0\text{ V to }3.6\text{ V}$; $V_{CC} = 0\text{ V to }3.6\text{ V}$	-	-	± 0.5	μA
I_{OFF}	power-off leakage current	V_I or $V_O = 0\text{ V to }3.6\text{ V}$; $V_{CC} = 0\text{ V}$	-	-	± 0.5	μA
ΔI_{OFF}	additional power-off leakage current	V_I or $V_O = 0\text{ V to }3.6\text{ V}$; $V_{CC} = 0\text{ V to }0.2\text{ V}$	-	-	± 0.6	μA
I_{CC}	supply current	$V_I = \text{GND or } V_{CC}$; $I_O = 0\text{ A}$; $V_{CC} = 0.8\text{ V to }3.6\text{ V}$	-	-	0.9	μA
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 0.6\text{ V}$; $I_O = 0\text{ A}$; $V_{CC} = 3.3\text{ V}$	-	-	50	μA
$T_{amb} = -40\text{ }^{\circ}\text{C to }+125\text{ }^{\circ}\text{C}$						
V_{IH}	HIGH-level input voltage	$V_{CC} = 0.8\text{ V}$	$0.75 \times V_{CC}$	-	-	V
		$V_{CC} = 0.9\text{ V to }1.95\text{ V}$	$0.70 \times V_{CC}$	-	-	V
		$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	1.6	-	-	V
		$V_{CC} = 3.0\text{ V to }3.6\text{ V}$	2.0	-	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 0.8\text{ V}$	-	-	$0.25 \times V_{CC}$	V
		$V_{CC} = 0.9\text{ V to }1.95\text{ V}$	-	-	$0.30 \times V_{CC}$	V
		$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	-	-	0.7	V
		$V_{CC} = 3.0\text{ V to }3.6\text{ V}$	-	-	0.9	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = 20\text{ }\mu\text{A}$; $V_{CC} = 0.8\text{ V to }3.6\text{ V}$	-	-	0.11	V
		$I_O = 1.1\text{ mA}$; $V_{CC} = 1.1\text{ V}$	-	-	$0.33 \times V_{CC}$	V
		$I_O = 1.7\text{ mA}$; $V_{CC} = 1.4\text{ V}$	-	-	0.41	V
		$I_O = 1.9\text{ mA}$; $V_{CC} = 1.65\text{ V}$	-	-	0.39	V
		$I_O = 2.3\text{ mA}$; $V_{CC} = 2.3\text{ V}$	-	-	0.36	V
		$I_O = 3.1\text{ mA}$; $V_{CC} = 2.3\text{ V}$	-	-	0.50	V
		$I_O = 2.7\text{ mA}$; $V_{CC} = 3.0\text{ V}$	-	-	0.36	V
		$I_O = 4.0\text{ mA}$; $V_{CC} = 3.0\text{ V}$	-	-	0.50	V
I_I	input leakage current	$V_I = \text{GND to }3.6\text{ V}$; $V_{CC} = 0\text{ V to }3.6\text{ V}$	-	-	± 0.75	μA
I_{OZ}	OFF-state output current	$V_I = V_{IH}$; $V_O = 0\text{ V to }3.6\text{ V}$; $V_{CC} = 0\text{ V to }3.6\text{ V}$	-	-	± 0.75	μA
I_{OFF}	power-off leakage current	V_I or $V_O = 0\text{ V to }3.6\text{ V}$; $V_{CC} = 0\text{ V}$	-	-	± 0.75	μA
ΔI_{OFF}	additional power-off leakage current	V_I or $V_O = 0\text{ V to }3.6\text{ V}$; $V_{CC} = 0\text{ V to }0.2\text{ V}$	-	-	± 0.75	μA
I_{CC}	supply current	$V_I = \text{GND or } V_{CC}$; $I_O = 0\text{ A}$; $V_{CC} = 0.8\text{ V to }3.6\text{ V}$	-	-	1.4	μA
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 0.6\text{ V}$; $I_O = 0\text{ A}$; $V_{CC} = 3.3\text{ V}$	-	-	75	μA

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 8](#).

Symbol	Parameter	Conditions	25 °C			−40 °C to +125 °C			Unit
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Max (125 °C)	
C _L = 5 pF									
t _{pd}	propagation delay	A to Y; see Figure 7	[2]						
		V _{CC} = 0.8 V	-	11.6	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.1	4.1	7.5	1.7	9.1	10.0	ns
		V _{CC} = 1.4 V to 1.6 V	1.6	3.0	5.1	1.3	6.1	6.7	ns
		V _{CC} = 1.65 V to 1.95 V	1.6	2.7	4.0	1.2	5.0	5.5	ns
		V _{CC} = 2.3 V to 2.7 V	1.1	2.1	3.2	0.9	4.0	4.4	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.2	2.8	1.1	3.3	3.6	ns
C _L = 10 pF									
t _{pd}	propagation delay	A to Y; see Figure 7	[2]						
		V _{CC} = 0.8 V	-	14.7	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.0	5.1	9.0	2.4	11.2	12.3	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	3.8	6.1	2.0	7.4	8.1	ns
		V _{CC} = 1.65 V to 1.95 V	2.4	3.6	4.8	1.8	6.1	6.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	2.8	3.8	1.3	4.8	5.3	ns
		V _{CC} = 3.0 V to 3.6 V	2.2	3.1	4.2	1.6	4.5	5.0	ns
C _L = 15 pF									
t _{pd}	propagation delay	A to Y; see Figure 7	[2]						
		V _{CC} = 0.8 V	-	17.7	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.5	6.1	10.4	3.2	13.1	14.5	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	4.5	6.8	2.6	8.6	9.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.8	4.4	6.7	2.2	7.8	8.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.4	3.4	4.5	1.9	5.3	5.8	ns
		V _{CC} = 3.0 V to 3.6 V	2.2	4.0	5.7	1.9	6.1	6.7	ns
C _L = 30 pF									
t _{pd}	propagation delay	A to Y; see Figure 7	[2]						
		V _{CC} = 0.8 V	-	24.6	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.8	9.0	15.6	4.3	18.8	20.7	ns
		V _{CC} = 1.4 V to 1.6 V	4.1	6.7	9.4	3.7	11.8	13.0	ns
		V _{CC} = 1.65 V to 1.95 V	3.8	6.8	9.7	3.2	11.0	12.1	ns
		V _{CC} = 2.3 V to 2.7 V	3.7	5.2	6.7	3.0	7.1	7.8	ns
		V _{CC} = 3.0 V to 3.6 V	3.6	6.4	9.7	2.8	10.4	11.4	ns

Table 8. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 8](#).

Symbol	Parameter	Conditions	25 °C			–40 °C to +125 °C			Unit
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Max (125 °C)	

$C_L = 5 \text{ pF}, 10 \text{ pF}, 15 \text{ pF}$ and 30 pF

C_{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz};$ $V_i = \text{GND to } V_{CC}$							pF
		$V_{CC} = 0.8 \text{ V}$	-	0.5	-	-	-	-	
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	-	0.6	-	-	-	-	
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	0.6	-	-	-	-	
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	0.7	-	-	-	-	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	0.9	-	-	-	-	
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	-	1.2	-	-	-	-	

[1] All typical values are measured at nominal V_{CC} .

[2] t_{pd} is the same as t_{PZL} and t_{PLZ} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

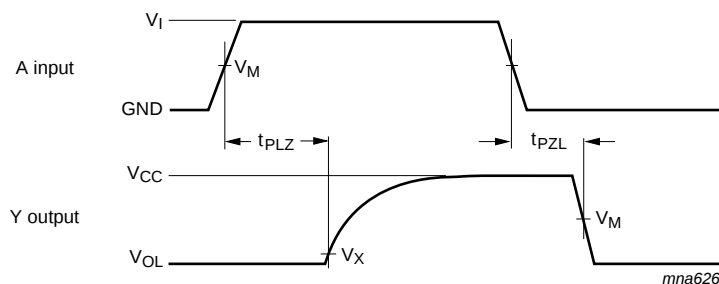
$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N$ where:

f_i = input frequency in MHz;

V_{CC} = supply voltage in V;

N = number of inputs switching.

12. Waveforms



Measurement points are given in [Table 9](#).

Logic level: V_{OL} is the typical output voltage drop that occur with the output load.

Fig 7. The data input (A) to output (Y) propagation delays**Table 9.** Measurement points

Supply voltage	Input	Output	
V_{CC}	V_M	V_M	V_X
0.8 V to 1.6 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$V_{OL} + 0.1 \text{ V}$
1.65 V to 2.7 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$V_{OL} + 0.15 \text{ V}$
3.0 V to 3.6 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$V_{OL} + 0.3 \text{ V}$

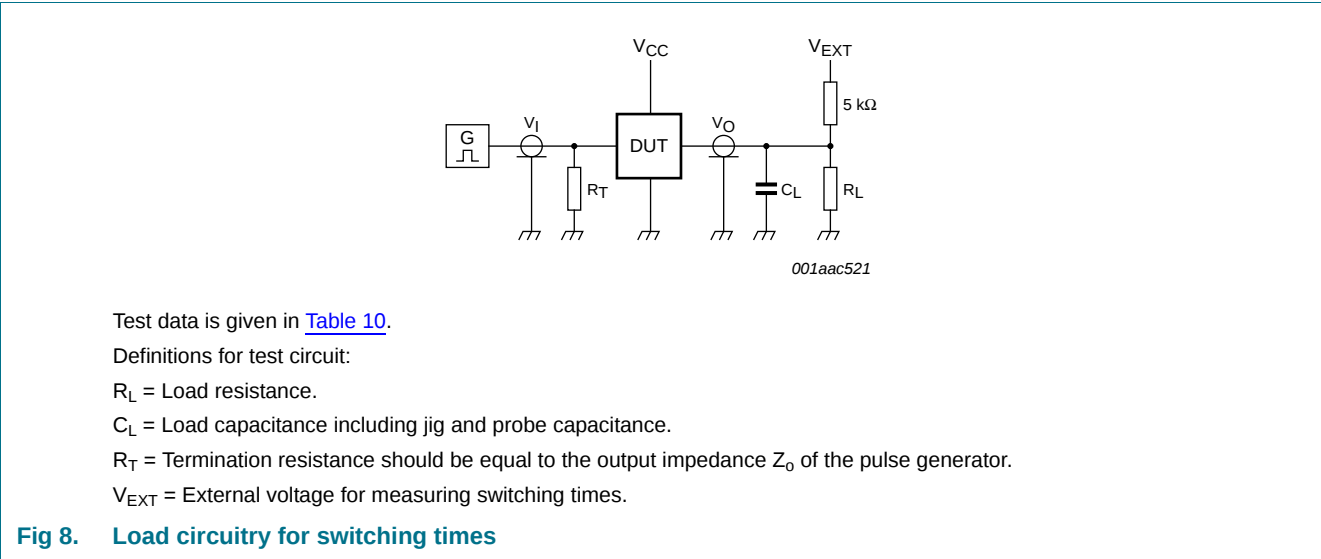


Table 10. Test data

Supply voltage	Load		V_{EXT}		
V_{CC}	C_L	R_L ^[1]	t_{PLH} , t_{PHL}	t_{PZH} , t_{PHZ}	t_{PZL} , t_{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times $R_L = 5\text{ k}\Omega$, for measuring propagation delays, setup and hold times and pulse width $R_L = 1\text{ M}\Omega$.

13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mmSOT353-1

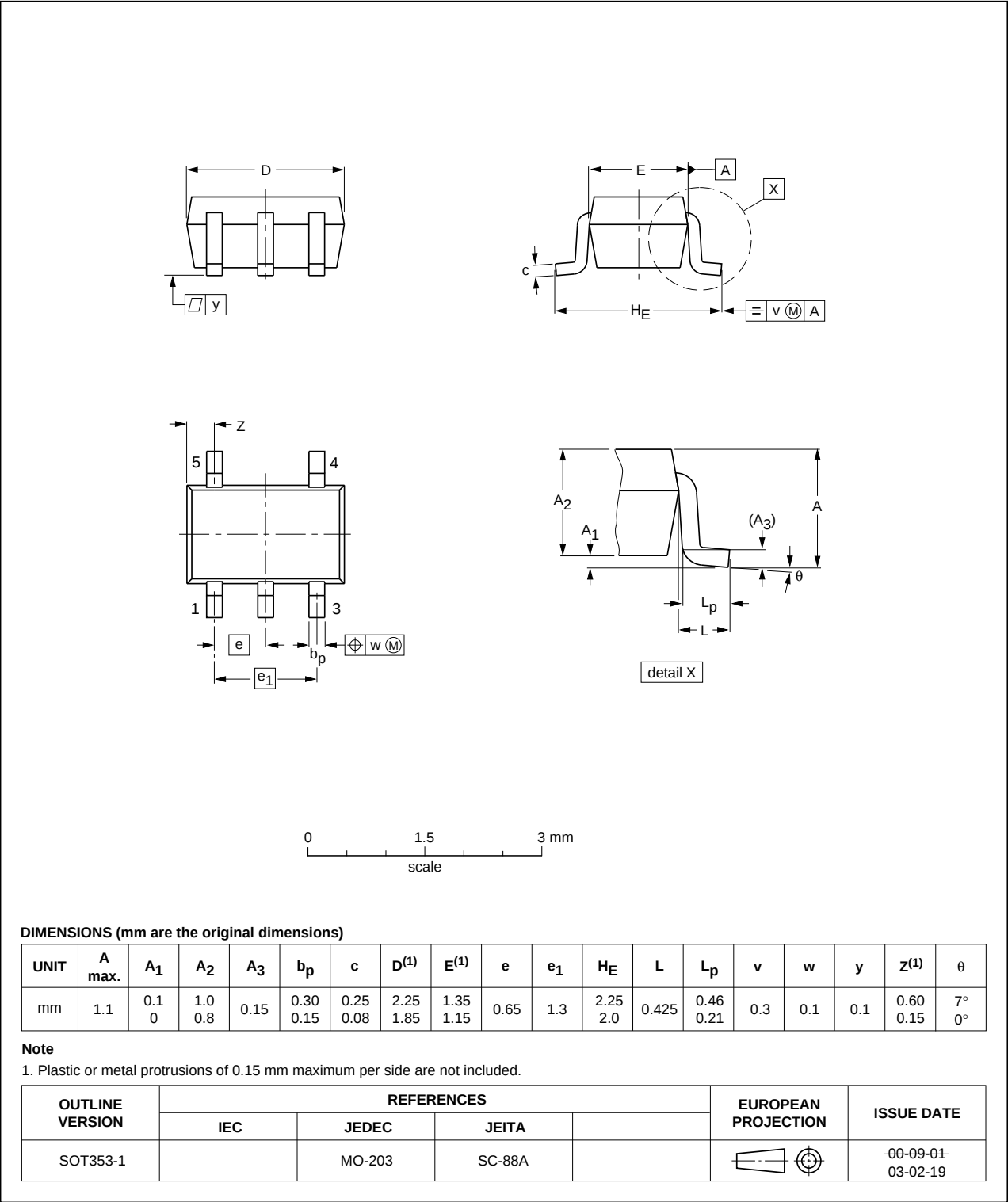


Fig 9. Package outline SOT353-1 (TSSOP5)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886

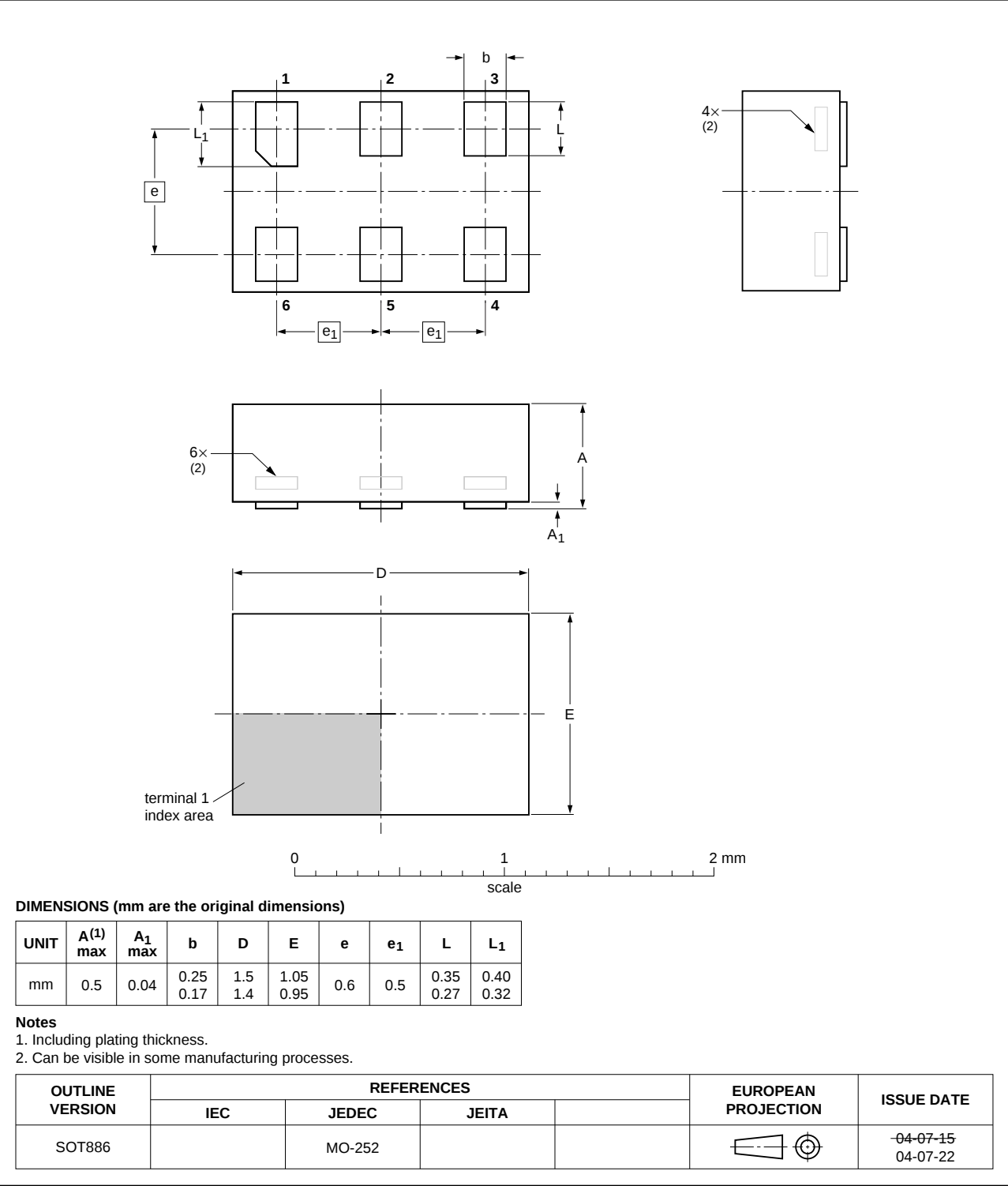
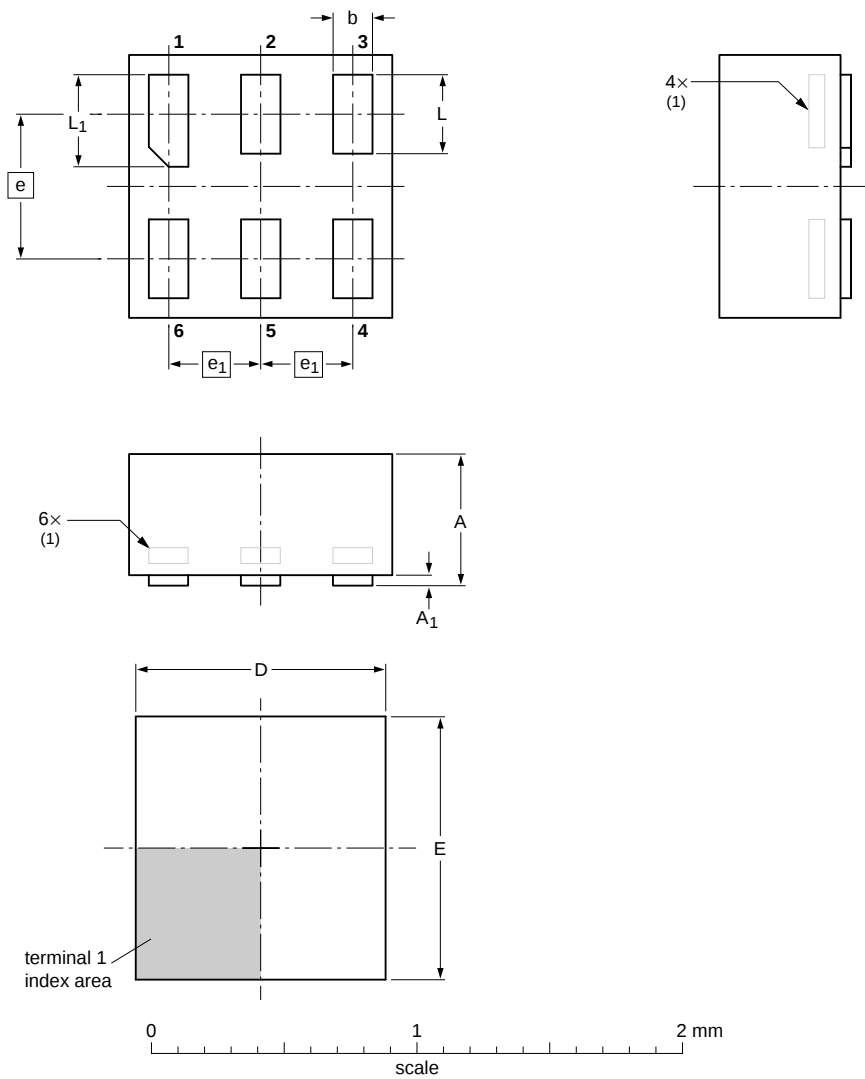


Fig 10. Package outline SOT886 (XSON6)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm

SOT891



DIMENSIONS (mm are the original dimensions)

UNIT	A _{max}	A _{1max}	b	D	E	e	e ₁	L	L ₁
mm	0.5	0.04	0.20 0.12	1.05 0.95	1.05 0.95	0.55	0.35	0.35 0.27	0.40 0.32

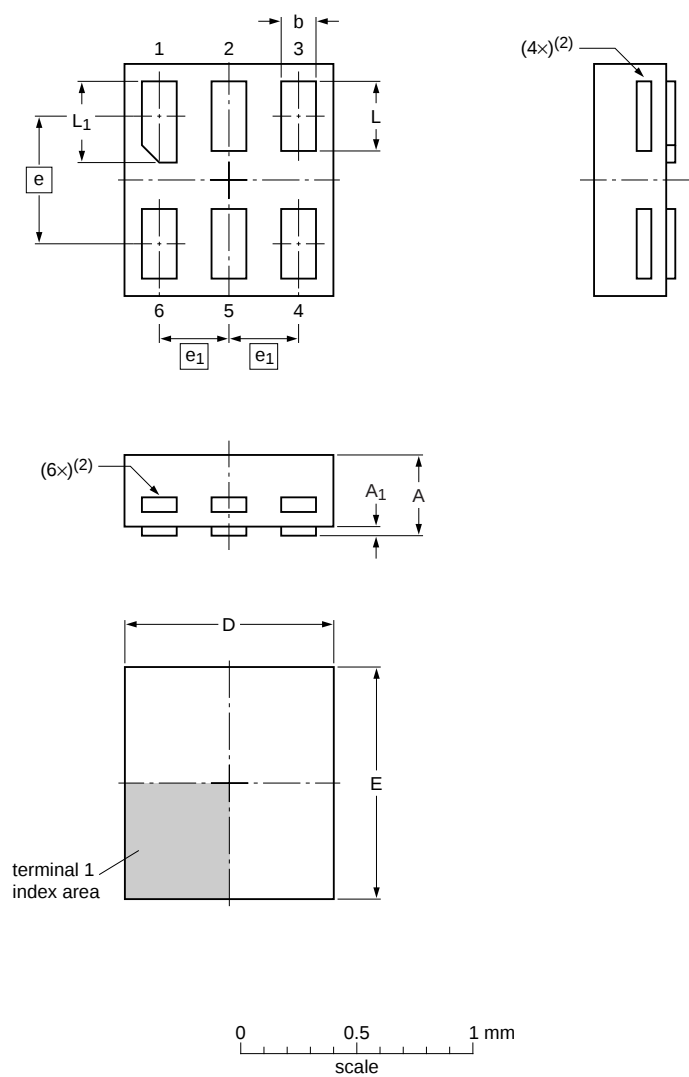
Note
1. Can be visible in some manufacturing processes.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT891						-05-04-06 07-05-15

Fig 11. Package outline SOT891 (XSON6)

XSON6: extremely thin small outline package; no leads;
6 terminals; body 0.9 x 1.0 x 0.35 mm

SOT1115



Dimensions

Unit	A ⁽¹⁾	A ₁	b	D	E	e	e ₁	L	L ₁
mm	max	0.35	0.04	0.20	0.95	1.05		0.35	0.40
	nom			0.15	0.90	1.00	0.55	0.30	0.35
	min			0.12	0.85	0.95		0.27	0.32

Note

- 1. Including plating thickness.
- 2. Visible depending upon used manufacturing technology.

sot1115_po

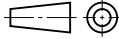
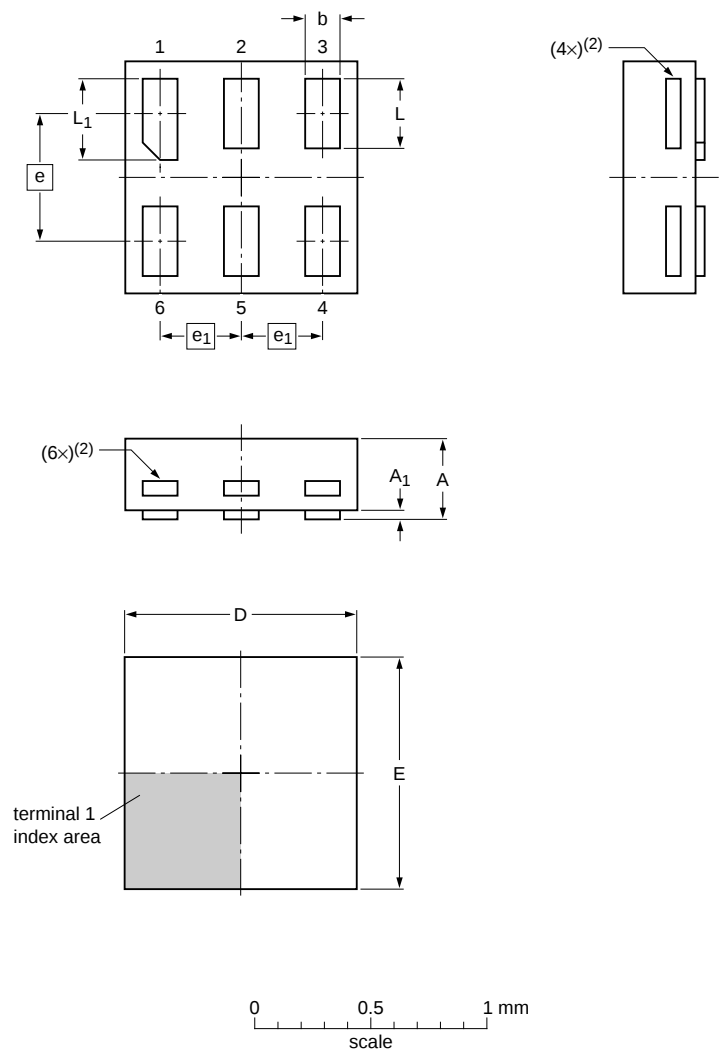
Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1115						10-04-02 10-04-07

Fig 12. Package outline SOT1115 (XSON6)

XSON6: extremely thin small outline package; no leads;
6 terminals; body 1.0 x 1.0 x 0.35 mm

SOT1202



Dimensions

Unit	A ⁽¹⁾	A ₁	b	D	E	e	e ₁	L	L ₁
mm	max	0.35	0.04	0.20	1.05	1.05		0.35	0.40
	nom			0.15	1.00	1.00	0.55	0.30	0.35
	min			0.12	0.95	0.95		0.27	0.32

Note

- 1. Including plating thickness.
- 2. Visible depending upon used manufacturing technology.

sot1202_po

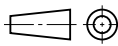
Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1202						10-04-02 10-04-06

Fig 13. Package outline SOT1202 (XSON6)

14. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

15. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G07 v.5	20111115	Product data sheet	-	74AUP1G07 v.4
Modifications:	• Legal pages updated.			
74AUP1G07 v.4	20100902	Product data sheet	-	74AUP1G07 v.3
74AUP1G07 v.3	20090617	Product data sheet	-	74AUP1G07 v.2
74AUP1G07 v.2	20070614	Product data sheet	-	74AUP1G07 v.1
74AUP1G07 v.1	20061010	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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